

MAZWxxxHG Series

Silicon planar type

For surge absorption circuit

■ Features

- Two elements anode-common type

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

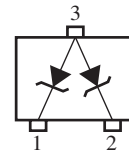
Parameter	Symbol	Rating	Unit
Total power dissipation *	P_{tot}	150	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Note) *: $P_{\text{tot}} = 150$ mW achieved with a printed circuit board.

■ Package

- Code
SSSMini3-F2
- Pin Name
1: Cathode 1
2: Cathode 2
3: Anode 1, 2

■ Internal Connection



■ Common Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Zener voltage *	V_Z	I_Z Specified value				V
Zener rise operating resistance	R_{ZK}	I_Z Specified value				Ω
Zener operating resistance	R_Z	I_Z Specified value				Ω
Reverse current	I_R	V_R Specified value				μA

Refer to the list of the electrical characteristics within part numbers

Note) 1. Measuring methods are based JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Electrostatic breakdown voltage is ± 10 kV

Test method: IEC1000-4-2 (C = 150 pF, R = 330 Ω , Contact discharge: 10 times)

3. *: The temperature must be controlled 25°C for V_Z measurement.

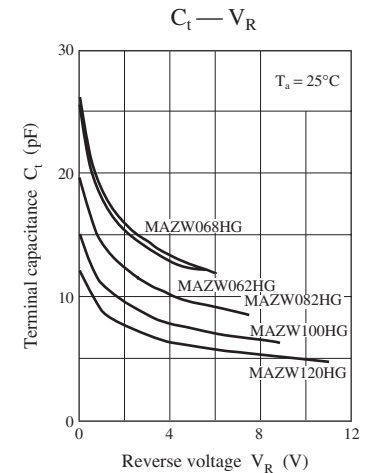
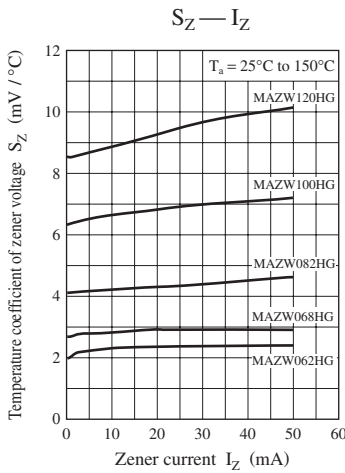
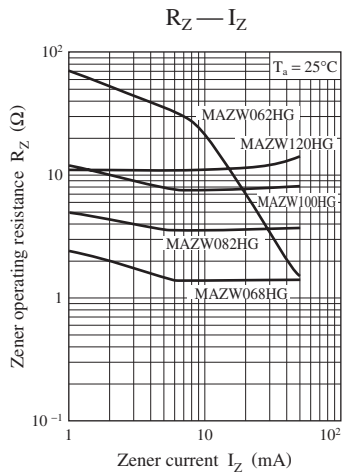
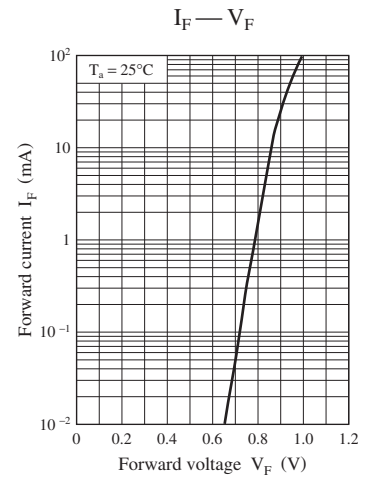
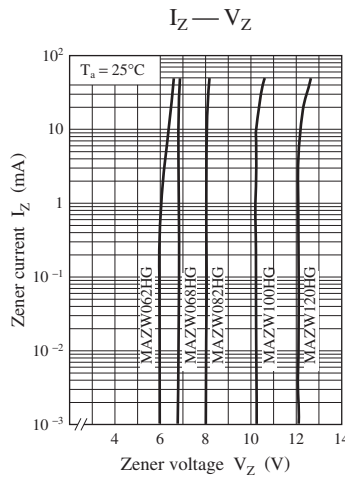
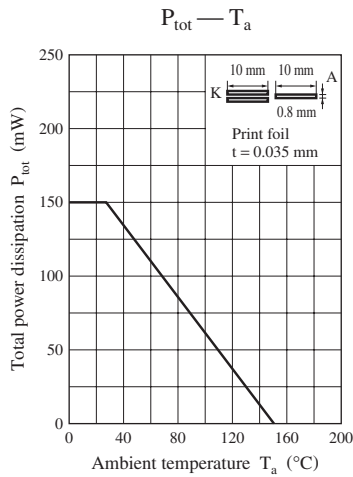
V_Z value measured at other temperature must be adjusted to $V_Z (25^\circ\text{C})$

V_Z guaranteed 20 ms after current flow.

■ Electrical characteristics within part numbers $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

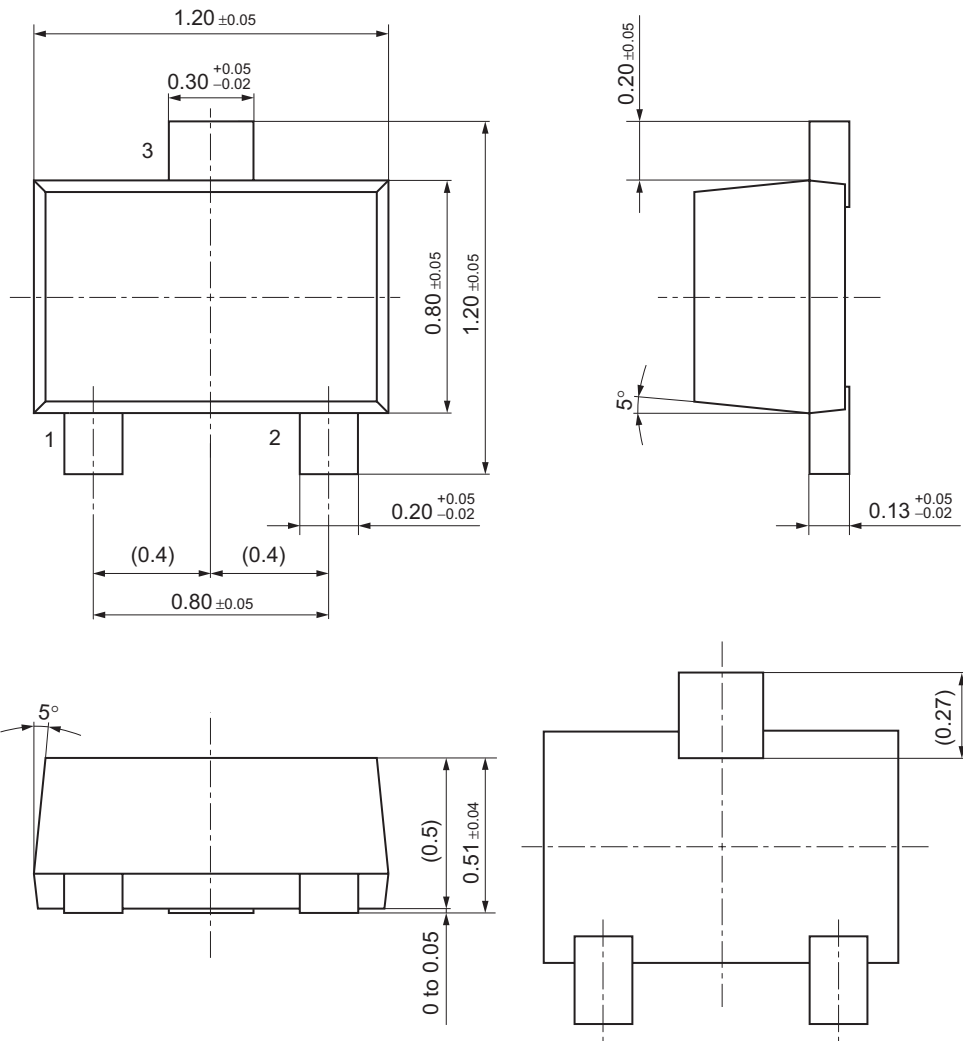
Part number	Zener voltage				Reverse current (DC)		Zener operating resistance		Marking symbol
	V_Z (V)				I_R (μA)		R_Z (Ω)	R_{ZK} (Ω)	
	Min	Nom	Max	I_Z (mA)	Max	V_R (V)	$I_Z = 5 \text{ mA}$ Max	$I_Z = 0.5 \text{ mA}$ Max	
MAZW062HG	5.8	6.2	6.6	5	0.2	4	50	100	62
MAZW068HG	6.4	6.8	7.2	5	0.1	4	30	60	68
MAZW082HG	7.7	8.2	8.7	5	0.1	5	30	60	82
MAZW100HG	9.4	10.0	10.6	5	0.05	7	30	60	10
MAZW120HG	11.4	12.0	12.7	5	0.05	9	30	60	12

- Note) 1. The V_Z value is the one after power application for 20 ms at $T_a = 25^\circ\text{C}$.
 2. The zener voltage temperature coefficient is the one for $T_j = 25^\circ\text{C}$ to 150°C .



SSSMini3-F2

Unit: mm



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